Features

- FCC approved method of EMI attenuation.
- Generates a 1X low EMI spread spectrum clock of the input frequency.
- Input frequency range: 20MHz –34MHz.
- Internal loop filter minimizes external components and board space.
- Frequency deviation: -1.5%
- Low inherent cycle-to-cycle jitter.
- 3.3V operating voltage.
- TTL or CMOS compatible inputs and outputs.
- Ultra-low power CMOS design.
 - o TBD mA @ 3.3V, 25MHz
 - o TBD mA @ 3.3V, 31MHz
- Pinout compatible with Cypress CY25811.
 Products are available for industrial temperature range.
- Available in 8-pin SOIC and TSSOP.

Product Description

The ASM3P5821A is a versatile spread spectrum frequency modulator designed specifically for input clock frequencies in the range of 20MHz - 34MHz. The ASM3P5821A can generate an EMI reduced clock from crystal, ceramic resonator, or system clock. The ASM3P5821A offers a percentage deviation of -1.5%.

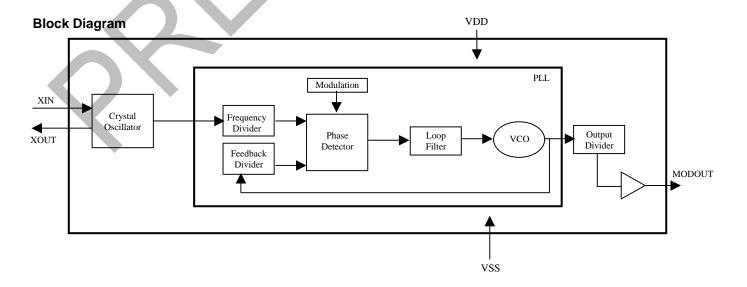
The ASM3P5821A reduces electromagnetic interference (EMI) at the clock source, allowing system wide reduction of EMI of down stream clock and data dependent signals. The ASM3P5821A allows significant system cost savings by reducing the number of circuit board layers ferrite beads, shielding and other passive components that are traditionally required to pass EMI regulations.

The ASM3P5821A uses the most efficient and optimized modulation profile approved by the FCC and is implemented in a proprietary all digital method.

The ASM3P5821A modulates the output of a single PLL in order to "spread" the bandwidth of a synthesized clock, and more importantly, decreases the peak amplitudes of its harmonics. This results in significantly lower system EMI compared to the typical narrow band signal produced by oscillators and most frequency generators. Lowering EMI by increasing a signal's bandwidth is called 'spread spectrum clock generation'.

Applications

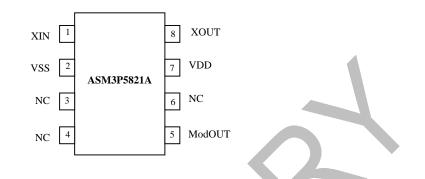
The ASM3P5821A is targeted towards EMI management for high speed digital applications such as PC peripheral devices, consumer electronics and embedded controller systems.



Alliance Semiconductor

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Pin Configuration



Pin Description

Pin#	Pin Name	Туре	Description
1	XIN	I	Crystal connection or external reference frequency input. This pin has dual functions. It can be connected to either an external crystal or an external reference clock.
2	VSS	Р	Ground to entire chip.
3	NC		No Connect.
4	NC		No Connect.
5	MODOUT	0	Spread spectrum low EMI output.
6	NC		No Connect.
7	VDD	Р	Power supply for the entire chip (3.3V).
8	XOUT	0	Crystal connection. If using an external reference clock, this pin must be left unconnected.

Low Power EMI Reduction IC

Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit			
VDD, V _{IN}	Voltage on any pin with respect to GND	-0.5 to + 7.0	V			
T _{STG}	Storage temperature	-65 to +125	°C			
T _A	Operating temperature	0 to 70	Э°			
Note: These are stress ratings only and functional operation is not implied. Exposure to absolute maximum ratings for extended periods may affect device reliability.						

DC Electrical Characteristics

Symbol	Parameter	Min	Тур	Max	Unit
V _{IL}	Input low voltage	GND – 0.3	-	TBD	V
V _{IH}	Input high voltage	TBD	-	V _{DD} + 0.3	V
I _{IL}	Input low current		TBD		μA
I _{IH}	Input high current		TBD		μA
I _{XOL}	XOUT output low current (@0.4V, V _{DD} =3.3V)		TBD		mA
I _{XOH}	XOUT output high current (@ 2.5V, V _{DD} =3.3V)	TBD			mA
V _{OL}	Output low voltage (V_{DD} = 3.3V, I_{OL} = 4mA)	TBD			V
V _{OH}	Output high voltage (V_{DD} = 3.3V, I_{OH} = 4mA)	TBD			V
I _{cc}	Dynamic supply current normal mode (3.3V and 10pF loading)	TBD			mA
I _{DD}	Static supply current standby mode				μA
V _{DD}	Operating voltage	TBD	3.3	TBD	V
t _{on}	Power up time (first locked clock cycle after power up)	-	TBD	-	mS
Z _{OUT}	Clock out impedance	-	TBD	-	Ω

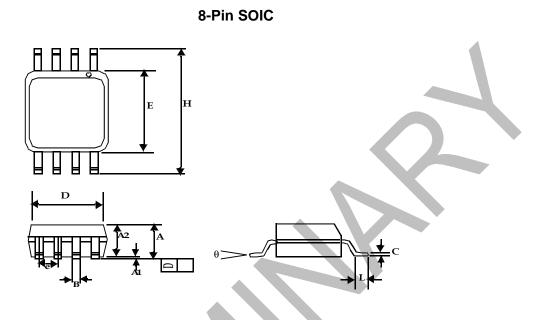
Low Power EMI Reduction IC

AC Electrical Characteristics

Symbol	Parameter	Min	Тур	Max	Unit	
XIN	Input frequency	20	25/31	34	MHz	
MODOUT	Output frequency	20	25/31	34	MHz	
t _{LH} *	Output rise time (measured at 0.8V to 2.0V)				ns	
t _{HL} *	Output fall time (measured at 2.0V to 0.8V)				ns	
t _{JC}	Jitter (cycle to cycle)	(1		TBD	ps	
t _D	Output duty cycle		TBD	-	%	
$^{*}t_{\text{LH}}$ and t_{HL} are measured into a capacitive load of 15pF						

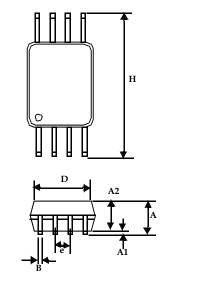


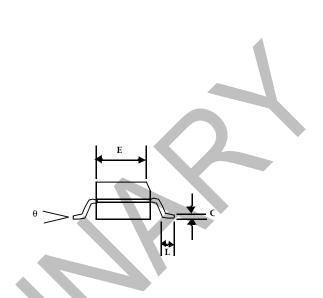
Package Information



Symbol	Dimensions	s in inches	Dimensions in millimeters		
	Min	Max	Min	Max	
A	0.057	0.071	1.45	1.80	
A1	0.004	0.010	0.10	0.25	
A2	0.053	0.069	1.35	1.75	
В	0.012	0.020	0.31	0.51	
С	0.004	0.01	0.10	0.25	
D	0.186	0.202	4.72	5.12	
E	0.148	0.164	3.75	4.15	
е	0.050	BSC	1.27 BSC		
н	0.224	0.248	5.70	6.30	
L	0.012	0.028	0.30	0.70	
	0°	8°	0°	8°	







	Dimension	s in inches	Dimensions in millimeters		
Symbol	Min	Max	Min	Max	
А	0.047			1.10	
A1	0.002	0.006	0.05	0.15	
A2	0.031	0.041	0.80	1.05	
В	0.007	0.012	0.19	0.30	
С	0.004	0.008	0.09	0.20	
D	0.114	0.122	2.90	3.10	
E	0.169	0.177	4.30	4.50	
е	0.026	BSC	0.65 BSC		
Н	0.244	0.260	6.20	6.60	
L	0.018	0.030	0.45	0.75	
θ	0°	8°	0°	8°	



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Low Power EMI Reduction IC